

TSHA5200, TSHA5201, TSHA5202, TSHA5203

Vishay Semiconductors

GREEN

Infrared Emitting Diode, 875 nm, GaAlAs



DESCRIPTION

The TSHA520. series are infrared, 875 nm emitting diodes in GaAlAs technology, molded in a clear, untinted plastic package.

FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

· Leads with stand-off

• Peak wavelength: $\lambda_p = 875 \text{ nm}$

· High reliability

• Angle of half intensity: $\phi = \pm 12^{\circ}$

· Low forward voltage

· Suitable for high pulse current operation

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- Infrared remote control and free air data transmission systems
- This emitter series is dedicated to systems with panes in transmission space between emitter and detector, because of the low absorbtion of 875 nm radiation in glass

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSHA5200	40	± 12	875	600	
TSHA5201	50	± 12	875	600	
TSHA5202	60	± 12	875	600	
TSHA5203	65	± 12	875	600	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
TSHA5200	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
TSHA5201	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
TSHA5202	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
TSHA5203	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			

Note

· MOQ: minimum order quantity



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5$, $t_p = 100 \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	2.5	Α	
Power dissipation		P _V	180	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W	

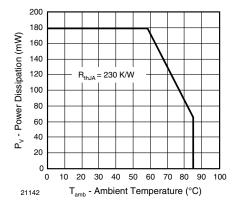


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

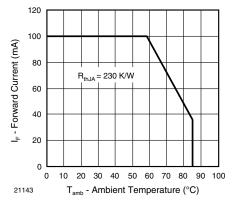


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	ON SYMBOL MIN. TYP. MAX		MAX.	. UNIT		
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.5	1.8	V	
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.6		mV/K	
Reverse current	V _R = 5 V	I _R			100	μA	
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	Cj		20		pF	
Temperature coefficient of φ _e	I _F = 20 mA	TKφ _e		- 0.7		%/K	
Angle of half intensity		φ		± 12		deg	
Peak wavelength	I _F = 100 mA	λρ		875		nm	
Spectral bandwidth	I _F = 100 mA	Δλ		80		nm	
Temperature coefficient of λ _p	I _F = 100 mA	TKλ _p		0.2		nm/K	
Rise time	I _F = 100 mA	t _r		600		ns	
Rise time	I _F = 1 A	t _r 300		ns			
Fall time	I _F = 100 mA	t _f		600	600 n:	ns	
raii uiile	I _F = 1 A	t _f		300		ns	
Virtual source diameter		d		3.7		mm	



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TYPE DEDICATED CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		TSHA5200	V_{F}		2.8	3.5	V
Forward voltage	L = 1 A + = 100 up	TSHA5201	V_{F}		2.8	3.5	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	TSHA5202	V_{F}		2.8	3.5	V
		TSHA5203	V _F		2.8	3.5	V
	100 00 00	TSHA5200	l _e	25	40	125	mW/sr
		TSHA5201	l _e	30	50	125	mW/sr
	$I_F = 100 \text{ mA}, t_p = 20 \mu \text{s}$	TSHA5202	l _e	36	60	125	mW/sr
Radiant intensity		TSHA5203	l _e	50	6 60 125 mW/s 0 65 125 mW/s 00 330 mW/s	mW/sr	
nadiant intensity		TSHA5200	l _e	200	330	3.5 3.5 3.5 125 125 125 125 125 1 125 1 10 110 110 110 110 110 110 110 110 1	mW/sr
	L = 1 A + = 100 up	TSHA5201	I _e	260	400		mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	TSHA5202	l _e	330	460		mW/sr
		TSHA5203	l _e	400	530		mW/sr
		TSHA5200	фe		22		mW
Dadient newer	100 4 + 00	TSHA5201	фe		23		mW
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \mu \text{s}$	TSHA5202	фe		24		V V V W/
		TSHA5203	фe		25	2.8 3.5 2.8 3.5 40 125 50 125 50 125 30 125 30 00 60 30 22 23 24	mW

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

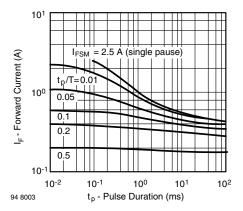


Fig. 3 - Pulse Forward Current vs. Pulse Duration

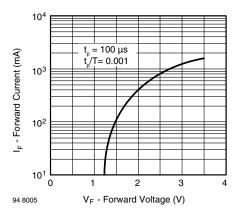


Fig. 4 - Forward Current vs. Forward Voltage

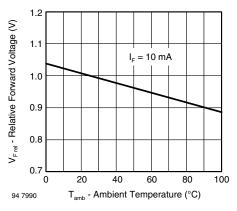


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

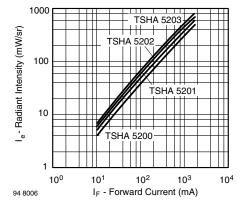


Fig. 6 - Radiant Intensity vs. Forward Current

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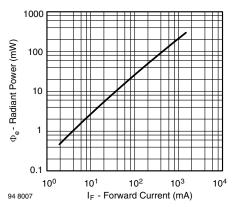


Fig. 7 - Radiant Power vs. Forward Current

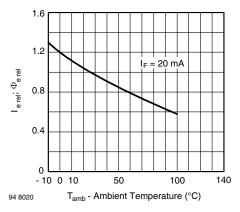


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

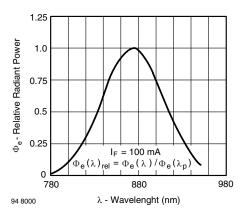


Fig. 9 - Relative Radiant Power vs. Wavelength

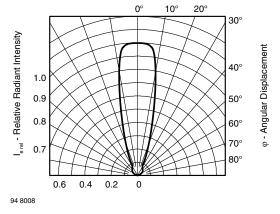
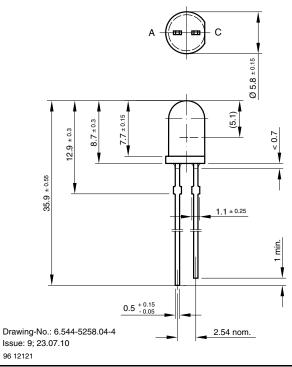
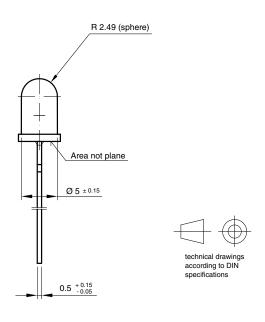


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters





Rev. 2.0, 24-Aug-11 **4** Document Number: 81019



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